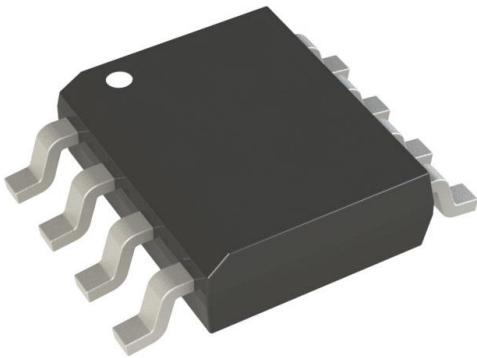


SQ4917CEY-T1_GE3 Datasheet

www.digi-electronics.com



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	SQ4917CEY-T1_GE3-DG
Manufacturer	Vishay Siliconix
Manufacturer Product Number	SQ4917CEY-T1_GE3
Description	MOSFET 2P-CH 60V 8A 8SOIC
Detailed Description	Mosfet Array 60V 8A (Tc) 5W (Tc) Surface Mount 8-S OIC

This model SQ4917CEY-T1_GE3 is available at DiGi Electronics.

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Manufacturer Product Number:

SQ4917CEY-T1_GE3

Series:

TrenchFET®

Technology:

MOSFET (Metal Oxide)

FET Feature:

-

Current - Continuous Drain (Id) @ 25°C:

8A (Tc)

Vgs(th) (Max) @ Id:

2.5V @ 250µA

Input Capacitance (Ciss) (Max) @ Vds:

1910pF @ 30V

Operating Temperature:

-55°C ~ 175°C (Tj)

Qualification:

AEC-Q101

Package / Case:

8-SOIC (0.154", 3.90mm Width)

Base Product Number:

SQ4917

Manufacturer:

Vishay Siliconix

Product Status:

Active

Configuration:

2 P-Channel (Dual)

Drain to Source Voltage (Vdss):

60V

Rds On (Max) @ Id, Vgs:

48mOhm @ 4.3A, 10V

Gate Charge (Qg) (Max) @ Vgs:

65nC @ 10V

Power - Max:

5W (Tc)

Grade:

Automotive

Mounting Type:

Surface Mount

Supplier Device Package:

8-SOIC

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

ECCN:

EAR99

Moisture Sensitivity Level (MSL):

1 (Unlimited)

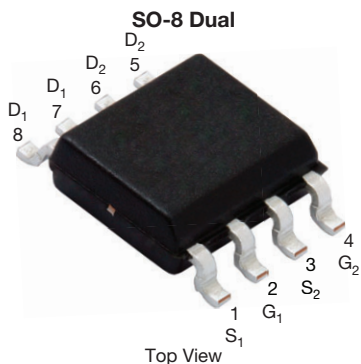
HTSUS:

8541.29.0095


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SQ4917CEY

Vishay Siliconix

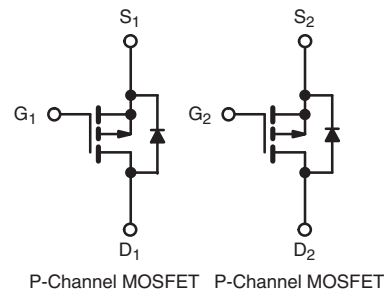
Automotive Dual P-Channel 60 V (D-S) 175 °C MOSFET



FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

 AUTOMOTIVE
GRADE

RoHS
COMPLIANT
HALOGEN
FREE


PRODUCT SUMMARY	
V _{DS} (V)	-60
R _{DS(on)} (Ω) at V _{GS} = -10 V	0.0480
R _{DS(on)} (Ω) at V _{GS} = -4.5 V	0.0612
I _D (A) per leg	-8
Configuration	Dual

ORDERING INFORMATION	
Package	SO-8
Lead (Pb)-free and halogen-free	SQ4917CEY (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	V _{DS}	-60	V
Gate-source voltage	V _{GS}	± 20	
Continuous drain current	I _D	T _C = 25 °C	-8
		T _C = 125 °C	-4.75
Continuous source current (diode conduction)	I _S	-4.5	A
Pulsed drain current ^a	I _{DM}	-32	
Single pulse avalanche current	I _{AS}	-22.4	
Single pulse avalanche energy	E _{AS}	25	mJ
Maximum power dissipation	P _D	T _C = 25 °C	5
		T _C = 125 °C	1.67
Operating junction and storage temperature range	T _J , T _{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-ambient	R _{thJA}	110	°C/W
Junction-to-foot (drain)	R _{thJF}	30	

Notes

- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %
- When mounted on 1" square PCB (FR-4 material)



SPECIFICATIONS ($T_C = 25\text{ }^\circ\text{C}$, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$		-60	-	-	V
Gate-source threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$		-1.5	-2.0	-2.5	
Gate-source leakage	I_{GSS}	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$		-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	$V_{GS} = 0\text{ V}$	$V_{DS} = -60\text{ V}$	-	-	-1	μA
		$V_{GS} = 0\text{ V}$	$V_{DS} = -60\text{ V}, T_J = 125\text{ }^\circ\text{C}$	-	-	-50	
		$V_{GS} = 0\text{ V}$	$V_{DS} = -60\text{ V}, T_J = 175\text{ }^\circ\text{C}$	-	-	-150	
On-state drain current ^a	$I_{D(on)}$	$V_{GS} = -10\text{ V}$	$V_{DS} \leq -5\text{ V}$	-30	-	-	A
Drain-source on-state resistance ^a	$R_{DS(on)}$	$V_{GS} = -10\text{ V}$	$I_D = -4.3\text{ A}$	-	0.0421	0.0480	Ω
		$V_{GS} = -10\text{ V}$	$I_D = -4.3\text{ A}, T_J = 125\text{ }^\circ\text{C}$	-	-	0.0780	
		$V_{GS} = -10\text{ V}$	$I_D = -4.3\text{ A}, T_J = 175\text{ }^\circ\text{C}$	-	-	0.0960	
		$V_{GS} = -4.5\text{ V}$	$I_D = -3.8\text{ A}$	-	0.0566	0.0612	
Forward transconductance ^b	g_{fs}	$V_{DS} = -15\text{ V}, I_D = -4.3\text{ A}$		-	12	-	S
Dynamic ^b							
Input capacitance	C_{iss}	$V_{GS} = 0\text{ V}$	$V_{DS} = -30\text{ V}, f = 1\text{ MHz}$	-	1575	1910	μF
Output capacitance	C_{oss}			-	175	417	
Reverse transfer capacitance	C_{rss}			-	113	142	
Total gate charge ^c	Q_g	$V_{GS} = -10\text{ V}$	$V_{DS} = -30\text{ V}, I_D = -5\text{ A}$	-	36.3	65	nC
Gate-source charge ^c	Q_{gs}			-	5.3	-	
Gate-drain charge ^c	Q_{gd}			-	8.9	-	
Gate resistance	R_g	f = 1 MHz		1.3	2.36	4	Ω
Turn-on delay time ^c	$t_{d(on)}$	$V_{DD} = -30\text{ V}, R_L = 8.8\text{ }\Omega$ $I_D \cong -5\text{ A}, V_{GEN} = -10\text{ V}, R_g = 1\text{ }\Omega$		-	11	17	ns
Rise time ^c	t_r			-	5	17	
Turn-off delay time ^c	$t_{d(off)}$			-	32	52	
Fall time ^c	t_f			-	5	9	
Source-Drain Diode Ratings and Characteristics ^b							
Pulsed current ^a	I_{SM}			-	-	-32	A
Forward voltage	V_{SD}	$I_F = -2.8\text{ A}, V_{GS} = 0\text{ V}$		-	-0.79	-1.2	V
Body diode reverse recovery time	t_{rr}	$I_F = -2.5\text{ A}, di/dt = 100\text{ A}/\mu\text{s}$		-	29	58	ns
Body diode reverse recovery charge	Q_{rr}			-	44	88	nC
Reverse recovery fall time	t_a			-	24	-	ns
Reverse recovery rise time	t_b			-	5	-	
Body diode peak reverse recovery current	$I_{RM(REC)}$			-	-3.4	-	A

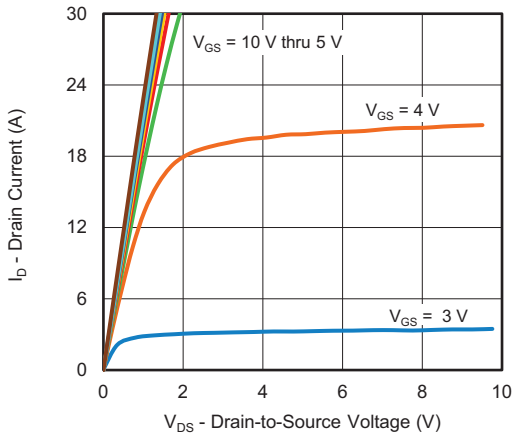
Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing
c. Independent of operating temperature

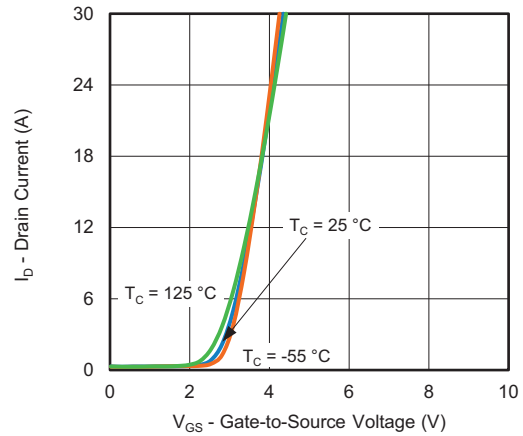
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



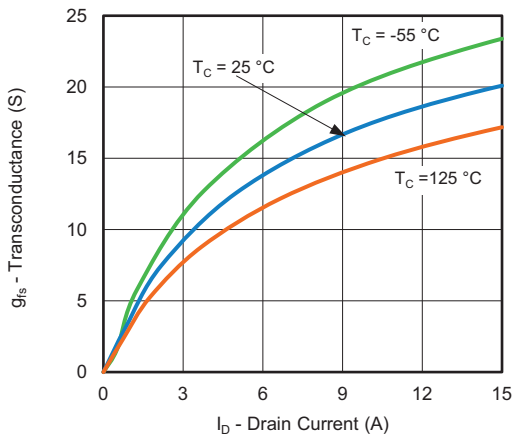
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



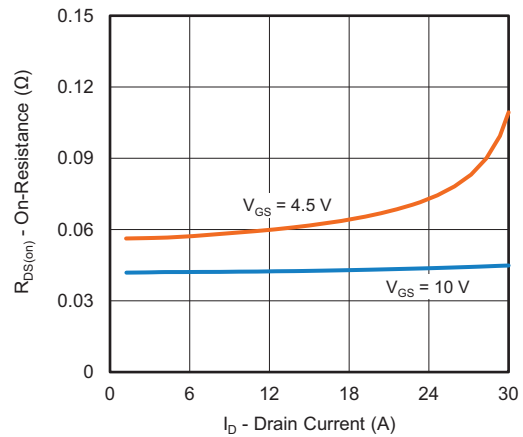
Output Characteristics



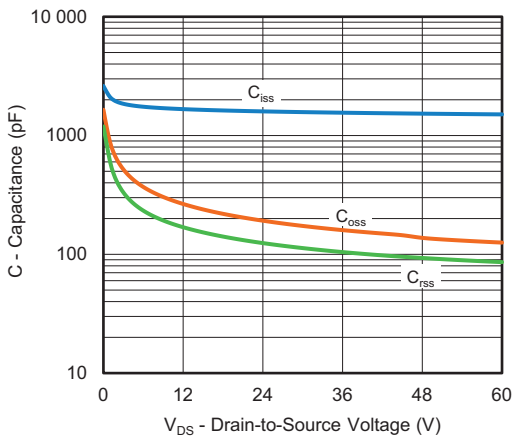
Transfer Characteristics



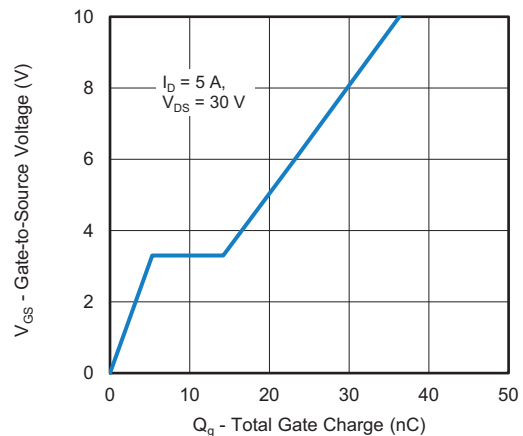
Transconductance



On-Resistance vs. Drain Current



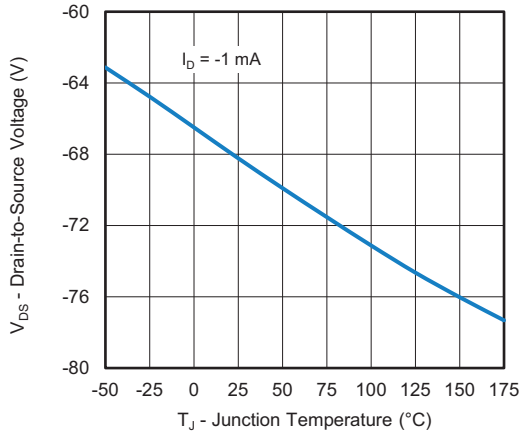
Capacitance



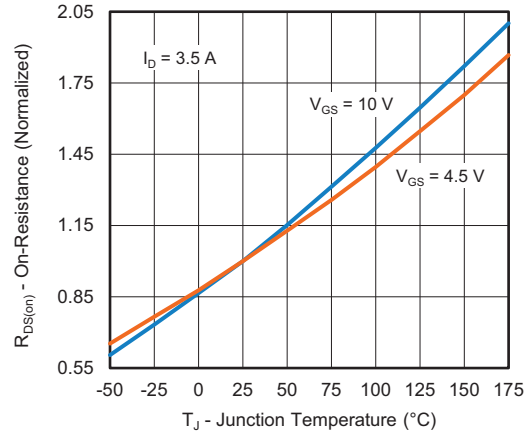
Gate Charge



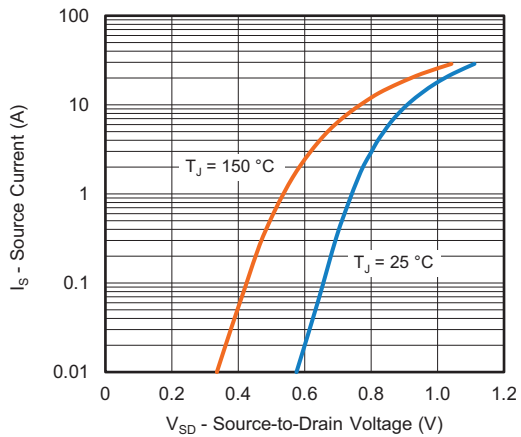
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



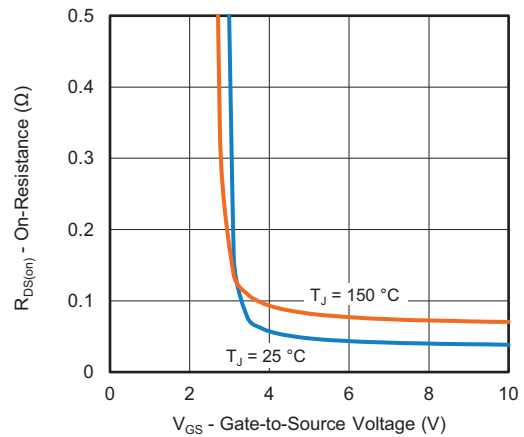
Drain Source Breakdown vs. Junction Temperature



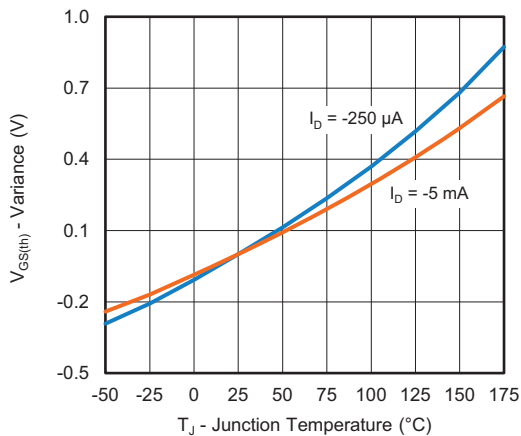
On-Resistance vs. Junction Temperature



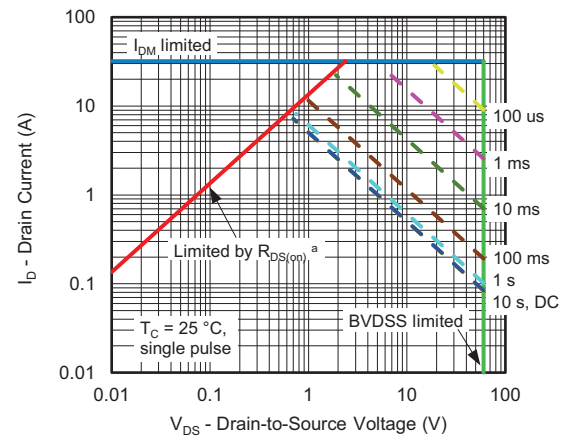
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



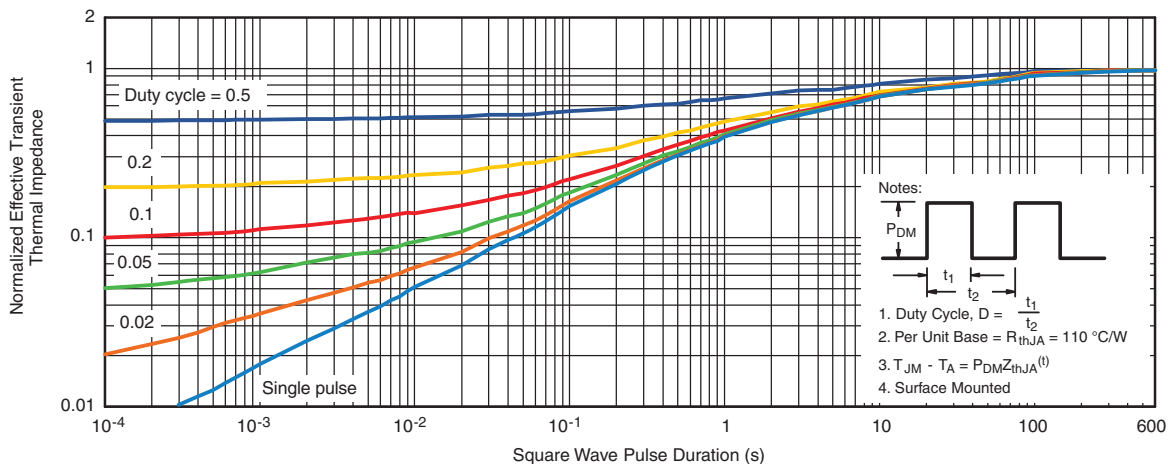
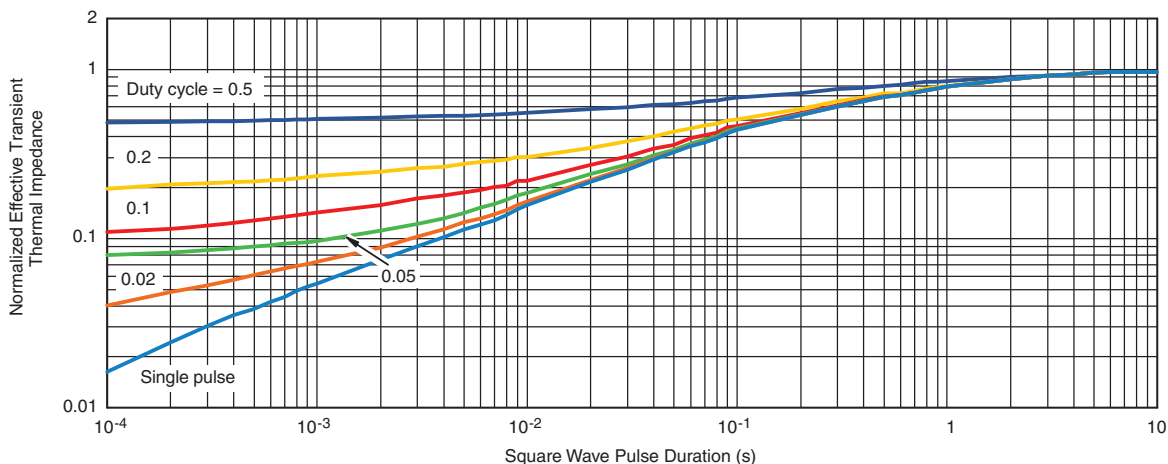
Threshold Voltage



Safe Operating Area

Note

- a. $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified


THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)

Normalized Thermal Transient Impedance, Junction-to-Ambient

Normalized Thermal Transient Impedance, Junction-to-Foot
Note

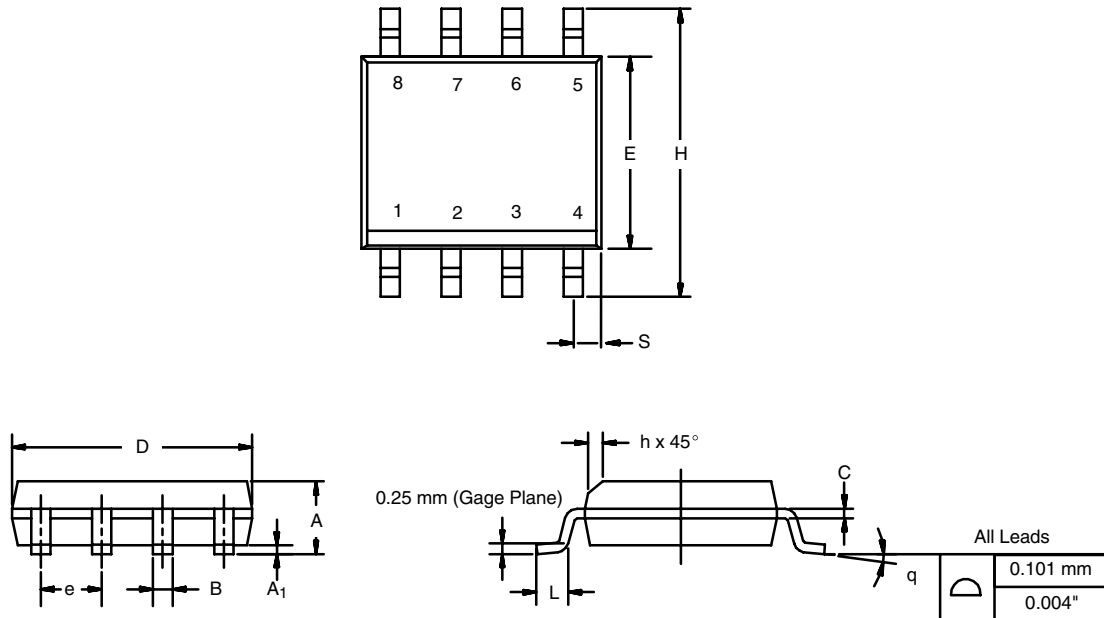
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient ($25\text{ }^\circ\text{C}$)
 - Normalized Transient Thermal Impedance Junction-to-Foot ($25\text{ }^\circ\text{C}$)
 are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62019.



SOIC (NARROW): 8-LEAD

JEDEC Part Number: MS-012



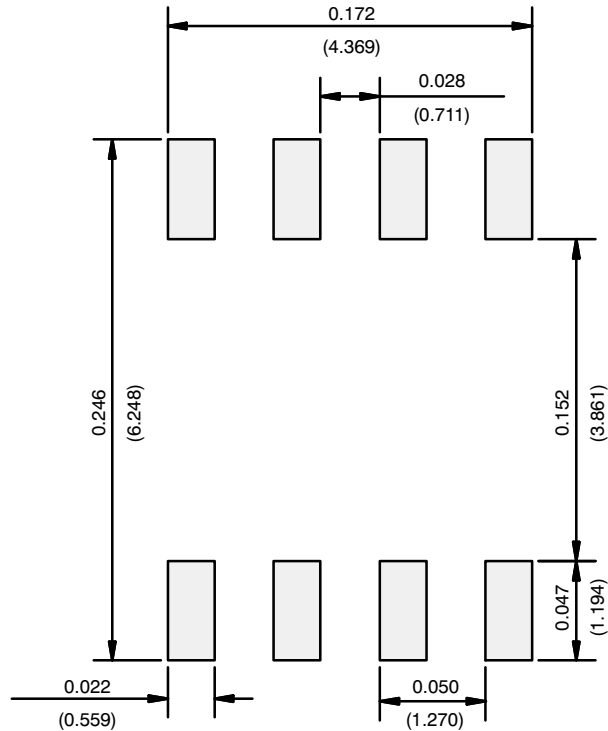
DIM	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
B	0.35	0.51	0.014	0.020
C	0.19	0.25	0.0075	0.010
D	4.80	5.00	0.189	0.196
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°
S	0.44	0.64	0.018	0.026
ECN: C-06527-Rev. I, 11-Sep-06				
DWG: 5498				

Application Note 826

Vishay Siliconix



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads
Dimensions in Inches/(mm)

[Return to Index](#)



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